

Docket No. IRV1.PAU.30



Patent Application

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of :

Douglas M. Albert et al.

Serial No.: 09/190,378

Filed: November 10, 1998

For: METHOD FOR THINNING
SEMICONDUCTOR WAFERS
WITH CIRCUITS AND WAFERS
MADE BY THE SAME

Examiner: D. Graybill

Group Art Unit: 3722

Irvine, California

October 22, 2001

DECLARATION OF INVENTOR VOLKAN H. OZGUZ
SWEARING BEHIND REFERENCE
(37 CFR § 1.131)

Assistant Commissioner for Patents
Washington, DC 20231

Dear Sir:

I, Volkan H. Ozguz, hereby declare as follows:

1. I am an inventor in this application. I am making this declaration to establish facts showing that the invention claimed in this application was reduced to practice before February 7, 1996, which I am informed is the filing date of the application that issued to Alan J. Riding et al. as U.S. Patent No. 6,083,811 ('811 Patent). I will hereinafter refer to February 7, 1996 as the "Effective Date" of the '811 Patent.

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2. I am employed by the assignee, Irvine Sensors Corporation ("ISC"). I work at ISC's Costa Mesa facility in the State of California. I have been employed continuously by ISC at all times relevant hereto

3. I have read Claims 1-32 that are pending in this application and have a technical understanding of how such claims apply to the disclosure of this application.

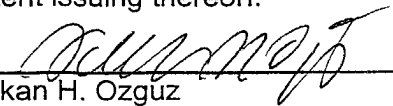
4. As a co-inventor, I actively collaborated with Mr. Albert in the development of the claimed invention and am personally familiar with the development of the invention claimed in our patent application. I have reviewed the fully-executed DECLARATION OF DOUGLAS M. ALBERT SWEARING BEHIND REFERENCE, including Exhibits "A" and "B" attached thereto. I hereby adopt and incorporate by reference the content of paragraphs 4 to 6 of Mr. Albert's declaration and the attached Exhibits "A" and "B", as if such descriptions were fully set forth herein and such exhibits were attached hereto.

5. This declaration factually establishes that the claimed invention was reduced to practice in the United States prior to the Effective Date of the '811 Patent.

6. I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements are made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under § 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

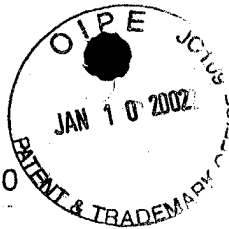
10/19/2001.

Date



Volkan H. Ozguz

Docket No. IRV1.PAU.30



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Irvine, California

October 22, 2001

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DECLARATION OF DOUGLAS M. ALBERT
SWEARING BEHIND REFERENCE
(37 CFR § 1.131)

Assistant Commissioner for Patents
Washington, DC 20231

Dear Sir:

I, Douglas M. Albert, hereby declare as follows:

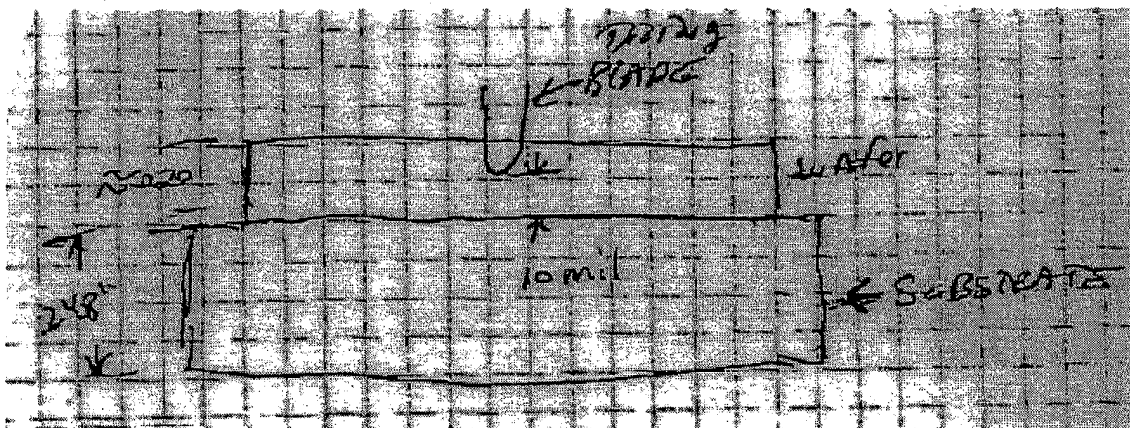
1. I am a co-inventor of the invention disclosed and claimed in patent application no. 09/190,378. I am making this declaration to establish facts showing that the invention claimed in this application was reduced to practice before February 7, 1996, which I am informed is the filing date of the application that issued to Alan J. Riding et al. as U.S. Patent No. 6,083,811 ('811 Patent). I will hereinafter refer to February 7, 1996 as the "Effective Date" of the '811 Patent.

2. I am employed by the assignee, Irvine Sensors Corporation ("ISC"). I work at ISC's Costa Mesa facility in the State of California. I have been employed continuously by ISC at all times relevant hereto

3. I have read Claims 1-32 that are pending in this application and have a technical understanding of how such claims apply to the disclosure of this application. As shown by the exhibits that I have attached hereto, Mr. Ozguz and I developed the method for thinning semiconductor wafers that is described and claimed in our patent application before the Effective Date of the '811 Patent.

4. Attached hereto as Exhibit A, for example, is a page from my inventor's notebook entitled "Grinding with Diced Wafers", dated "7/27/95", which describes and illustrates the claimed invention as follows:

Theory – Dice wafers partially through leaving 10 mil of [silicon] between bottom of cut and bottom of wafer. After dicing, mount wafer to substrate and grind past depth of dicing cut, therefore leaving chips mounted to substrate as opposed to a wafer.



5. At the bottom of Exhibit A are detailed observations regarding three actual "results", i.e. evidence of an actual reduction to practice of our claimed invention at least as of July 27, 1995, prior to the Effective Date of the '811 Patent.

6. Also attached hereto as Exhibit B is a written "Status Report" that I prepared on or about "8-1-95". The memo further corroborates our having successfully back-ground partially diced wafers, in the manner claimed in our patent application, prior to the Effective Date of the '811 Patent.

7. This declaration factually establishes that the claimed invention was reduced to practice in the United States prior to the Effective Date of the '811 Patent.

8. I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements are made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under § 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

10/19/2001
Date


Douglas M. Albert

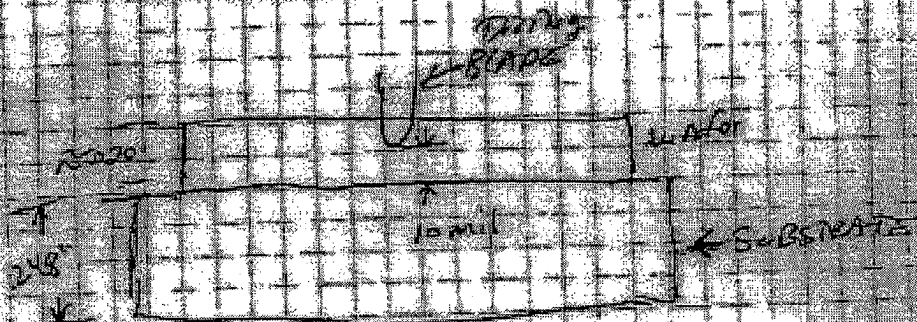
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HDIOT

7/27/95

GLYING WITH
DRED WATER

THICK - DRE WATER PRIMARY GROUTS LEAVING
10 MIL OF S. BETWEEN BOTTOM OF CUT
AND BOTTOM OF WATER AFTER DRED MOVED
WATER TO SUBSTRATE AND GROUND POST PART
OF DRED CUT THICKER LEAVING CHAS. MOVED
TO SUBSTRATE OR APPLIED TO A WATER



pieces:
DRE WATER ON CUT THE DRE LEAVING 10
MILS OF S. (SEE SIDE SIDE S.B.)
DRED TAP AND WAX MOVED WATER TO
SUBSTRATE DIZING SIDE DOWN PRESS WAS (STICK WAS SENT
WITH NO PSI PRESS AND ALLOW TO COOL UNDER
PRESSURE AND GROUND

SUBSTRATE 4307 AG. OF TAP TAPED
LIMAS

Parts
#1 3 pul/sec DRED TO 6457
(Gnd 4 mil) 1 pul/sec GROUND 6107
TO GROUND GND

OBSERVATIONS
CHAS MOVED OUTWARD
FROM CORNER OF SUBSTRATE
LOS OF CHAS MOVEMENT
GND THICKNESS WAS GOOD
CHAS MOVED BUT NOT LOW
THAN 1/2 IN. BASED ON THAT
OBSERVATION DECIDED TO FINISH
GND
GND THICKNESS GOOD

#2 2 pul/sec Repro to 6457
1 pul/sec CORNER 6407
NO GROUND

#3 3 pul/sec Repro to 6420
1 pul/sec CORNER to 6422
25 pul/sec GROUND 6401

CHAS - CHAS MOVED OUTWARD
OUTSIDE CHAS MOVED MORE
THAN CORNER CHAS
GND THICKNESS
GOOD

HDIOI STATUS REPORT

IRVINE SENSORS CORP.

Subject: Present Wafer Thinning Experiment Status

To: Angel Pepe, Dave Ludwig

From: Doug Albert

Date: 8-1-95

CC: K.G., Y.H.

Conclusion:

Based on my experiments up to this point it appears clear to me that in order to ultimately thin wafers to 10 μ m a wafer backing medium will be necessary. The challenge I was handed was to see how thin a 5" wafer could be mechanically be ground. Considering there really was no spec. established for mechanical grinding, my goal was to go as thin as possible. The initial thoughts of mounting and grinding wafers on UV tape and processing them on the tape now look dismal. The thinnest wafer that was ground with NO breakage was 4 mills and even that is NOT repeatable. Also, demounting the UV tape from a wafer that is very thin proved very difficult and seems to me a high risk approach.

A second approach was to mount a wafer to a substrate with some sort of adhesive then thin and process the wafer on the substrate. Presently this method is working fairly well. I have been thinning 4" wafers submounted to Macor substrates using a variety of adhesives. I have successfully thinned and demounted 2 mil wafers and ground 1 wafer to 20 μ m (not demounted). The process does appear to be pretty repeatable. By far the most touchy area is demounting and propagation of cracking from wafer edge. Note: The program calls for thinning 5" wafers for which the substrates are on order. Until proper substrates are received and tried nothing is for sure.

To go one step further, in order to eliminate crack propagation across a wafer and isolate chips within a substrate a chip isolation process was born. By dicing partially through a wafer, mounting the diced surface down toward the substrate and grinding down past the diced grooves, chips were created hence eliminating crack propagation. This also creates chips alleviating the need to create chips using a lithographic process using plasma etching. I am still working some small movement problems with this process. I am also still establishing my thinning limits with this process as well.

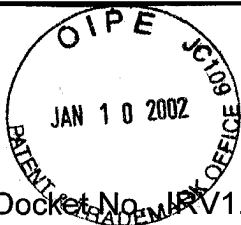
All in all things look positive. I am continuing with experiments and will have a more in depth report upon completion of the experiments. I presently do not see any major roadblocks. I am confident that the present problems can be solved.

Diced Submount Thinning

The next step was to see if we could eliminate the need to dice streets after the thinning in order to create chips. By performing the chip isolation early in the process we now will only lose a chip in the event of a crack or breakage. The way this was performed was to dice partially into a wafer mount the diced side down and backgrind the wafer submounted to the substrate. When the wafer was ground past the depth of the dicing and the grinding was complete you had chips mounted on a substrate. The wax did fill the dicing grooves and acted as a barrier once the grooves were reached from grinding. This reduced edge damage from grinding process. The thinnest I have been able to grind using this method is approx. 4 mils (101µm).

Problems

1. One problem with the thinner wax was chip movement. Reduced feed rates helped slightly.
2. The thicker stronger bond waxes had air pockets and were too viscous thus not allowing good squeeze out of adhesive.
3. The stronger bond adhesives tended to load the grinding wheel.
4. The stronger waxes are slightly harder to demount but not a roadblock.



Docket No. 1998-11-PAU.30

Patent Application

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Douglas M. Albert,
Volkan H. Ozguz

Examiner: David E. Graybill

Serial No.: 09/190,378

Group Art Unit: 2814

Filed: November 10, 1998

For: METHOD FOR THINNING
SEMICONDUCTOR WAFERS
WITH CIRCUITS AND WAFERS
MADE BY THE SAME

Irvine, California

December 13, 2001

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DECLARATION OF JOSEPH C. ANDRAS

Assistant Commissioner for Patents
Washington, D.C. 20231

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JAN 15 2002

OFFICE OF PETITIONS

Dear Sir:

I, Joseph C. Andras, hereby declare as follows:

1. I am an attorney admitted to practice law in the State of California and the attorney of record in U.S. Patent Application No. 09/190,378 entitled "Method For Thinning Semiconductor Wafers With Circuits And Wafers Made By The Same."
2. Attached hereto under Tab "A" is a copy of the Notice of Abandonment that we just received.
3. Attached hereto under Tab "B" is a true and correct copy of the papers that we filed on October 22, 2001, in response to the Office Action of April 20, 2001, including: (1) a response entitled AMENDMENT "A"; (2) Declaration of Douglas M. Albert; (3) Declaration of Inventor Volkan H. Ozguz; (4) a Request for Three-Month

Extension of Time; (5) a check to cover the extension fee in the amount of \$460.00; and (6) a postcard listing all the foregoing items.

4. In view of the fact that we timely filed the attached Response, it is respectfully submitted that the abandonment was issued in error or that the application has been unavoidably abandoned. We respectfully request, therefore, that the Office withdraw the abandonment or revive the application.

I declare under penalty of perjury that the foregoing is true and correct.

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Assistant Commissioner for Patents, Washington, DC 20231 on December

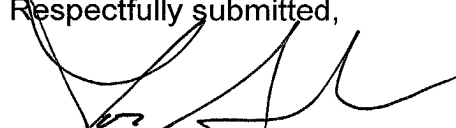
14, 2001

Angela Williams



Signature
December 14, 2001

Respectfully submitted,


Joseph C. Andras
Registration No. 33,469
Myers Dawes & Andras LLP
19900 MacArthur Blvd, Suite 1150
Irvine, CA 92612

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UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
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Washington, D.C. 20231
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/190,378	11/10/1998	DOUGLAS M. ALBERT	IRV1.PAU.30	6576

7590 11/26/2001
JOSEPH C ANDRAS
650 TOWN CENTER DRIVE
SUITE 650
COSTA MESA, CA 92626

EXAMINER

GRAYBILL, DAVID E

ART UNIT	PAPER NUMBER
----------	--------------

2814

DATE MAILED: 11/26/2001

Please find below and/or attached an Office communication concerning this application or proceeding.

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2001

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Notice of Abandonment

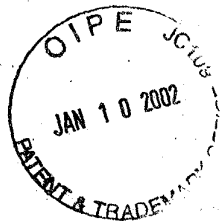
Application No.	Applicant(s)	
09/190,378	ALBERT, DOUGLAS M.	
Examiner	Art Unit	
David E Graybill	2814	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address--

This application is abandoned in view of:

1. ☒ Applicant's failure to timely file a proper reply to the Office letter mailed on 20 April 2001.
 - (a) ☐ A reply was received on _____ (with a Certificate of Mailing or Transmission dated _____), which is after the expiration of the period for reply (including a total extension of time of _____ month(s)) which expired on _____.
 - (b) ☐ A proposed reply was received on _____, but it does not constitute a proper reply under 37 CFR 1.113 (a) to the final rejection.
(A proper reply under 37 CFR 1.113 to a final rejection consists only of: (1) a timely filed amendment which places the application in condition for allowance; (2) a timely filed Notice of Appeal (with appeal fee); or (3) a timely filed Request for Continued Examination (RCE) in compliance with 37 CFR 1.114).
 - (c) ☒ No reply has been received.
2. ☐ Applicant's failure to timely pay the required issue fee and publication fee, if applicable, within the statutory period of three months from the mailing date of the Notice of Allowance (PTOL-85).
 - (a) ☐ The issue fee and publication fee, if applicable, was received on _____ (with a Certificate of Mailing or Transmission dated _____), which is after the expiration of the statutory period for payment of the issue fee (and publication fee) set in the Notice of Allowance.
 - (b) ☐ The submitted fee of \$_____ is insufficient. A balance of \$_____ is due.
The issue fee required by 37 CFR 1.18 is \$_____. The publication fee, if required by 37 CFR 1.18(d), is \$_____.
 - (c) ☐ The issue fee and publication fee, if applicable, has not been received.
3. ☐ Applicant's failure to timely file new formal drawings as required by, and within the three-month period set in, the Notice of Allowability (PTO-37).
 - (a) ☐ Proposed new formal drawings were received on _____ (with a Certificate of Mailing or Transmission dated _____), which is after the expiration of the period for reply.
 - (b) ☐ The proposed new formal drawings filed on _____ are not acceptable and the period for reply has expired.
 - (c) ☐ No proposed new formal drawings have been received.
4. ☐ The letter of express abandonment which is signed by the attorney or agent of record, the assignee of the entire interest, or all of the applicants.
5. ☐ The letter of express abandonment which is signed by an attorney or agent (acting in a representative capacity under 37 CFR 1.34(a)) upon the filing of a continuing application.
6. ☐ The decision by the Board of Patent Appeals and Interference rendered on _____ and because the period for seeking court review of the decision has expired and there are no allowed claims.
7. ☐ The reason(s) below:

David E Graybill
Primary Examiner
Art Unit: 2814



**The official stamp of the PTO hereon
acknowledges receipt of:**

Date: October 22, 2001
Serial No.: 09/190,378
Client: IRVINE SENSORS
For: METHOD FOR THINNING
SEMICONDUCTOR WAFERS
WITH CIRCUITS AND WAFERS
MADE BY THE SAME
Atty. Dkt. No.: IRV1.PAU.30

Enclosed:

1. Amendment "A" (12 pages)
2. Declaration of Douglas M. Albert (6 pages)
3. Declaration of Inventor Volkan H. Ozguz (2 pages)
4. Request for Three-Month Extension of Time (1 page + duplicate)
5. Check No. 4401 in the amount of \$460.00
6. Return Postcard

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MYERS, DAWES & ANDRAS LLP
19900 MACARTHUR BLVD, STE 1150 (949) 223-9600
IRVINE, CA 92612

CALIFORNIA FEDERAL BANK
COSTA MESA, CA 92626
907177/3222/721

4401

10/20/2001

PAY TO THE ORDER OF Assistant Commissioner For Patents

\$ 460.00

Four Hundred Sixty and 00/100

DOLLARS

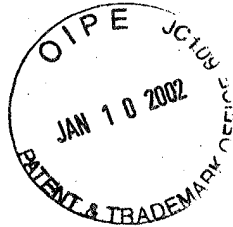
MEMO IRV1.PAU.30, JCA
Serial No. 09/190,378, 3-Month Extension Fee


AUTHORIZED SIGNATURE

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MYERS, DAWES & ANDRAS LLP

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